

FAST HIGH VOLTAGE TRANSISTOR SWITCHES

DESCRIPTION

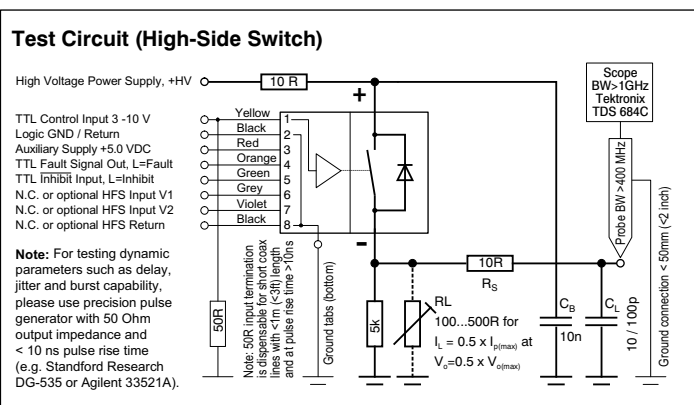
The high-voltage switches described here have a variable on-time and are comparable with classical solid-state relays; they are turned on as long as a control signal is applied to the control input. BEHLKE HTS switches are actively controlled devices (no avalanche technique) and show highly reliable and reproducible switching behaviour regardless of temperature, voltage or load condition. Compared to conventional high voltage switching elements, such as gas discharge tubes and spark gaps, BEHLKE solid-state switches do not show aging effects and achieve life times by several orders of magnitude higher than any other classical high voltage switch.

The switches are very easy to handle and only require a simple +5 VDC auxiliary supply (4.5 to 5.5 VDC) and a TTL-compatible control signal. The control signal can be any positive going pulse of at least 25 ns duration and 2 to 10 volts amplitude. Due to the Schmitt-Trigger input characteristics and the very high signal amplification neither the switching behavior nor the turn-on rise time will be influenced by the waveshape of the control pulse. The recovery time after a switching cycle is less than 150 ns, making burst frequencies of up to 6 MHz possible. Burst frequencies of even up to 10 MHz can be achieved by means of the option **HFB**. The maximum continuous switching frequency is primarily limited by the power capability of the internal driver and by the power dissipation of the high-voltage switch. Standard switches without optional cooling and without optional **HFS** supply can reach several 10 kHz, depending on operating voltage and load capacitance. Higher frequencies require an additional auxiliary supply for the internal driver, which is connected by means of the option **HFS**. The switch must also be sufficiently cooled if the frequency depending power dissipation exceeds the specified $P_{d(max)}$ value. For the individual cooling requirements are various cooling features available, such as option **CCS** (ceramic cooling surface), **CF** (copper cooling fins), **CF-CER** (ceramic cooling fins), **CF-GRA** (graphite cooling fins), **GCF** (grounded cooling flange), **ILC** (indirect liquid cooling) or **DLC** (direct liquid cooling). In connection with option **DLC** the continuous switching frequency can be increased up to 3 MHz.

The switches are equipped with the new "intelligent" driving and control circuit VC4, which provides active input filtering, signal conditioning, auxiliary voltage monitoring, frequency limitation and temperature protection. The input filter allows an unshielded input wiring of at least 25 cm (10") length. Undefined control signals, noise and transients are uncritical to the switch. The high-voltage MOSFET stack is always safely controlled regardless to the pulse width or waveshape of the control signal. The control circuit has 3 integrated temperature triggers. One thermotriple with a response time of <60 seconds protects the high-voltage switch, two further sensors with <10 seconds response time are placed in the critical areas of the driver circuit. An inhibit input (pin 5, L=Inhibit) allows the connection of external thermotriggers, over current detectors and / or coolant flow detectors from liquid cooling systems. The operating conditions are indicated by three built-in LEDs. In case of a fault (auxiliary voltage < 4.5 VDC, frequency > f(max), case temperature > 75°C and / or Inhibit = Low), the red LED will indicate an error and the switch is inhibited for at least 2 seconds respectively for the duration of the fault condition. At the same time a TTL compatible fault signal occurs at pin 4 (Low = Fault). In case of over temperature the switch can be locked for several minutes, depending on the individual cooling conditions. A green LED indicates "Ready for Operation" and a yellow LED indicates the on-state of the switch as well as short control pulses with a pulse duration down to 30 ns. The design concept of these switching modules offers a large selection of cooling and housing options as well as a very high flexibility regarding the adaption to individual OEM requirements. Please refer to the separate options page for some examples of individual switch solutions. In case the built volume is the main design concern, then the HTS compact series (HTS xx-xx-C) is recommended, which has widely the same electrical data except for Max. Power Dissipation and Max. Continuous Frequency.

CIRCUIT DESIGN RECOMMENDATIONS

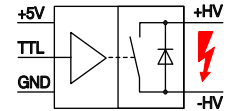
In order to achieve the minimum turn-on rise time and the best HV pulse shape, all leads and circuit paths should be of lowest possible inductance. This can be achieved by means of very wide and short circuit tracks on the printed circuit board, if necessary in several layers (multi layer PCB). Part components such as R_s , C_{sp} and C_b must be "inductance-free" and should only be connected with shortest possible wires / circuit tracks. Ground conducting tracks including the logic ground must be connected to a common ground point (star-type ground). Induction loop areas of dynamically current-carrying circuit paths should always be as small as possible. HV wiring and control circuitry should always be separated by a proper distance. For further design recommendations please refer to the general instructions.



HTS 61-02	6000 VDC / 25 A (pk)
HTS 61-05	6000 VDC / 50 A (pk)
HTS 101-01	10000 VDC / 15 A (pk)
HTS 101-03	10000 VDC / 30 A (pk)
HTS 151-01	15000 VDC / 12 A (pk)
HTS 151-02	15000 VDC / 24 A (pk)

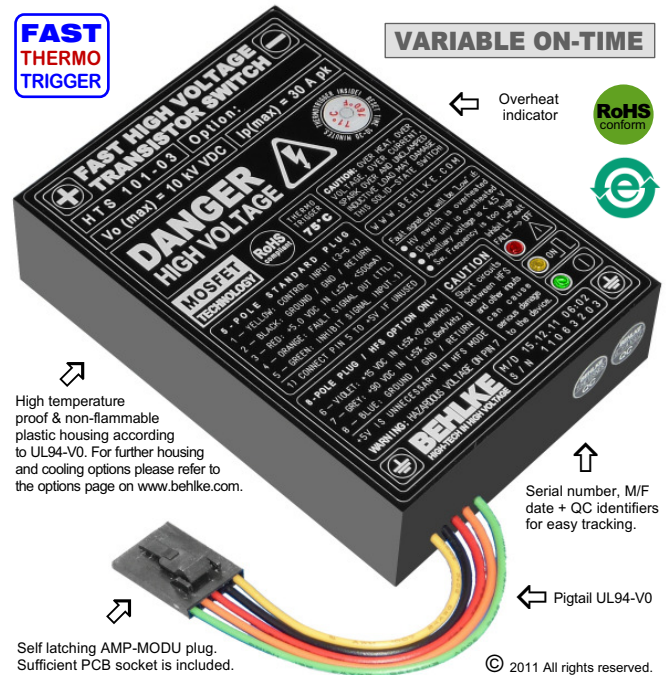
MOSFET TECHNOLOGY

VC4 DRIVER

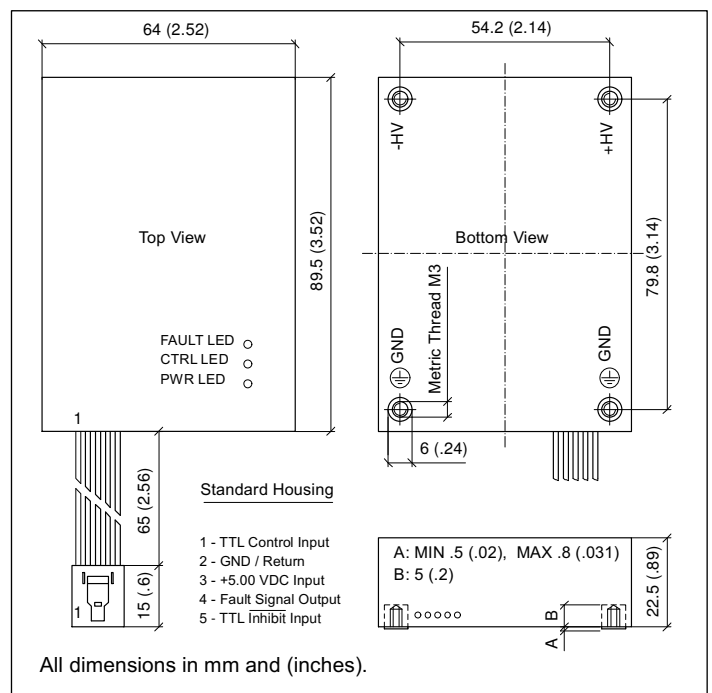


FAST THERMO TRIGGER

VARIABLE ON-TIME



5 ns Rise Time • 3 MHz Rep Rate
6 MHz Burst • $t_{(on)} = 50 \text{ ns} \dots \infty$



Specification	Symbol	Condition / Comment	HTS	61-02	61-05	101-01	101-03	151-01	151-02	Unit
Maximum Operating Voltage	$V_{O(max)}$	$I_{off} < 50 \mu ADC$, $T_{case} = 70^\circ C$		± 6.0	± 6.0	± 10.0	± 10.0	± 15.0	± 15.0	kVDC
Maximum Isolation Voltage	V_i	Between HV switch and control / GND, continuously		± 30						kVDC
Max. Housing Insulation Voltage	V_{INS}	Between switch and housing surface, 3 minutes		± 40						kVDC
Maximum Turn-On Peak Current	$I_{P(max)}$	$T_{case} = 25^\circ C$ $t_p < 200 \mu s$, duty cycle $< 1\%$		25	50	15	30	12	24	ADC
Maximum Continuous Load Current	I_L	$T_{case} = 25^\circ C$ $T_{fin} = 25^\circ C$ $T_{flange} = 25^\circ C$ $T_{inlet} = 25^\circ C$ Standard devices & FC, forced air 4 m/s Devices with option CF, forced air 4 m/s Devices with option GCF, on heat sink. Devices with option ILC, water 0.1 l/min. Devices with option DLC-0.2 (DLC-1.0)		0.75	1.04	0.38	0.53	0.36	0.51	ADC
Max. Continuous Power Dissipation	$P_{d(max)}$	$T_{case} = 25^\circ C$ $T_{fin} = 25^\circ C$ $T_{flange} = 25^\circ C$ $T_{inlet} = 25^\circ C$ Standard devices & FC, forced air 4 m/s Devices with option CF, forced air 4 m/s Devices with option GCF on heat sink. Devices with option ILC, water > 0.1 l/min Devices with option DLC-0.2 (DLC-1.0)		15 100 150 150 200 (1000)						
Linear Derating		Above $25^\circ C$ Standard devices & FC, forced air 4 m/s Devices with option CF, forced air 4 m/s Devices with option GCF, on heat sink. Devices with option ILC, water 0.1 l/min. Devices with option DLC-0.2 (DLC-1.0)		0.33 2.22 3.33 3.33 5.71 (28.6)						W/K
Operating Temperature Range	T_O	Standard devices & options CF, GCF, ILC. (Option DLC)		-40...70 (60)						$^\circ C$
Storage Temperature Range	T_S	Switches with option ILC may require frost protection!		-50...100						$^\circ C$
Max. Permissible Magnetic Field	B	Homogeneous steady-field, surrounding the whole switch		25						mT
Operating Voltage Range	V_O	Positive or negative voltage (depending on connection)		0 - 6.0	0 - 10.0			0 - 15.0		kVDC
Typical Breakdown Voltage	V_{br}	NOTE: V_{br} is a test parameter for quality control purposes only. Not applicable in normal operation! $I_{off} > 0.5 mA$		6.6	11.0			16.5		kVDC
Typical Off-State Current	I_{off}	$25^\circ C$, @ $0.8xV_O$. Lower leakage current optionally available.		< 10						μADC
Typical Turn-On Resistance	R_{stat}	$T_{case} = 25^\circ C$, $T_{flange} = 25^\circ C$, $T_{fin} = 25^\circ C$, $T_{inlet} = 25^\circ C$. $0.1 x I_{P(max)}$ $1.0 x I_{P(max)}$		12	6	40	20	60	30	Ohm
Typical Propagation Delay Time	$t_{d(on)}$	Resistive load, $0.1 x I_{P(max)}$, $0.8 x V_{O(max)}$, 50-50%		100						
Typical Output Pulse Jitter	t_j	Impedance matched input, $V_{aux} / V_{ctrl} = 5.00 VDC$		< 500						ps
Typical Turn-On Rise Time	$t_{r(on)}$	10-90%, t_r can be customized in certain limits. $R_L = 5k\Omega$, $0.2 x V_{O(max)}$, $C_L = 10pF$ $R_L = 5k\Omega$, $0.8 x V_{O(max)}$, $C_L = 10pF$ $R_L = 5k\Omega$, $0.8 x V_{O(max)}$, $C_L = 100pF$ $V_O = 0.5 x V_{O(max)}$, $I_L = 0.5 x I_{P(max)}$		3.4	3.3	4.9	5	5.8	4.5	ns
Typical Turn-Off Rise Time	$t_{r(off)}$	10-90%, resistive load @ $1.0 x I_{P(max)}$		6.4	4.9	9.5	8	13	11	
Maximum Turn-On Time	$t_{on(max)}$	No limitation, true on-off switch with relay character		20	16	36	22	56	33	ns
Minimum Turn-On Time	$t_{on(min)}$	10-90%, resistive load @ $1.0 x I_{P(max)}$		< 7	< 7	< 12	< 12	< 5	< 5	
Maximum Continuous Switching Frequency	$f_{(max)}$	@ $V_{aux} = 5.00 V$ Sw. shutdown if $f_{(max)}$ is exceeded Standard devices without HFS option Standard devices with HFS supply Opt. HFS + sufficient cooling option		> 22	> 40	> 22	> 40	> 20	> 38	kHz
Maximum Burst Frequency	$f_b(max)$			3000	1500	2000	1000	1500	750	
Maximum Number of Pulses / Burst	$N_{(max)}$	$f_b = 1MHz$ (1 μs spacing). Switch shutdown if $N_{(max)}$ is exceeded.		6	4	5	3	5	3	MHz
Coupling Capacitance	C_C	Switch against control side Standard devices & options CF, DLC Devices with options GCF, ILC		200 Use burst option HFB for > 200 pulses						Pulses
Natural Capacitance	C_N	Between switch poles, @ $0.5 x V_{O(max)}$		8 30 ... 60						pF
Control Voltage Range	V_{ctrl}	The V_{ctrl} has no impact on the output pulse shape.		5 10 4 8 5 10						pF
Auxiliary Supply Voltage Range	V_{aux}	The +5 V supply is not required in the HFS mode.		2 ... 6						VDC
Typical Auxiliary Supply Current	I_{aux}	$V_{aux} = 5.00 VDC$, $T_{case} = 25^\circ C$. Active current limitation above 700 mA. $0.01 x f_{(max)}$ @ specified $f_{(max)}$		4.5 ... 5.5						VDC
Opt. HFS, Ext. Supply Voltage V1	$V_{HFS(V1)}$	Stability $\pm 3\%$, current consumption $< 0.4 mA/kHz$ @ $25^\circ C$		100						mADC
Opt. HFS, Ext. Supply Voltage V2	$V_{HFS(V2)}$	Stability $\pm 3\%$, current consumption $< 0.5 mA/kHz$ @ $25^\circ C$		500						mADC
Intrinsic Diode Forward Voltage	V_F	$T_{case} = 25^\circ C$, $I_F = 0.3 x I_{P(max)}$		9	8.5			9		VDC
Diode Reverse Recovery Time	t_{rc}	$T_{case} = 25^\circ C$, $I_F = 0.3 x I_{P(max)}$, $di/dt = 100 A/\mu s$		660	600			520		ns
Dimensions		Standard housing Devices with option FC Devices with option CF Devices with option GCF / FH Devices with option ILC & DLC-0.2 (DLC-1.0 on request)		89 x 64 x 22.5 89 x 64 x 17 89 x 64 x 58 114 x 66 x 31 89 x 64 x 35						mm ³
Weight		Standard housing Devices with option FC Devices with option CF Devices with option GCF Devices with option ILC & DLC-0.2 (DLC-1.0 on request)		232 185 334 595 400						g
Control Signal Input		Pin 1 / Yellow (LS-C: Pin 1). TTL compatible (LS-C: With 100 Ω termination). Schmitt-Trigger characteristics. Control voltage 2-10 V (3-5 V for low jitter).								
Logic GND / 5V Return		Pin 2 / Black (LS-C: Shielding). The ground pin is internally connected with the safety earthings terminals (threaded inserts) on bottom side.								
5V Auxiliary Supply		Pin 3 / Red (LS-C: Pin 4). The 5 V input is used for rep rates up to the specified max. frequency $f_{(max)}$. Higher rep rates require option HFS.								
Fault Signal Output		Pin 4 / Orange (LS-C: Pin 3). TTL output, short circuit proof. Indicating switch & driver over-heat, over-frequency, low auxiliary voltage. L = Fault.								
Inhibit Signal Input		Pin 5 / Green (LS-C: Pin 2). TTL compatible, Schmitt-Trigger characteristics for the connection of external safety circuits. L = Switch Inhibited.								
LED Indicators		GREEN: "Auxiliary power good, switch OFF". YELLOW: "Control signal received, switch ON". RED: "Fault condition, switch OFF"								
Temperature Protection		A) Standard switches and switches with opt. FC, CF, GCF: Thermo trigger $75^\circ C$, response time $< 60 s$ @ $3xP_d(max)$, $\Delta T = 25K$ (50 to $75^\circ C$). Separate driver protection. B) Switches with option DLC: $65^\circ C$, response time $< 3 s$ @ $3xP_d(max)$, $\Delta T = 25K$ (40 to $65^\circ C$), coolant flow $> 3 l/min$. Separate driver protection.								
HTS 61-02	Fast HV Transistor Switch, 6kV, 25 A	Option MBC	Mechanical Backward Compatibility to HTS 81, 51, 31 ff.	Option CCS	Ceramic Cooling Surface. $P_{d(max)}$ can be increased by the factor 2 to 3.					
HTS 61-05	Fast HV Transistor Switch, 6kV, 50 A	Option LS-C	Shielded Control Input (LEMO socket). For EMC critical designs.	Option CF	Copper Cooling Fins. $P_{d(max)}$ can be increased by the factor 3 to 10.					
HTS 101-01	Fast HV Transistor Switch, 10kV, 15 A	Option HFS	High Frequency Switching (two auxiliary supply inputs V1 & V2)	Option GCF	Grounded Cooling Flange (copper). $P_{d(max)}$ can be increased by the factor 3 to 15.					
HTS 101-03	Fast HV Transistor Switch, 10kV, 30 A	Option LP	Low Pass. Input filter for increased noise immunity.	Option ILC	Indirect Liquid Cooling (for water). $P_{d(max)}$ can be increased by the factor 3 to 15.					
HTS 151-01	Fast HV Transistor Switch, 15kV, 12 A	Option UFR	Ultra Fast Thermotriiger. Response time for shut down $< 5s$.	Option DLC	Direct Liquid Cooling (for PPE/PFC). $P_{d(max)}$ can be increased by the factor 10 to 100.					
HTS 151-02	Fast HV Transistor Switch, 15kV, 24 A	Option UFTS	Ultra Fast Thermosensor. Response time $< 5s$. NTC 10k / $\pm 1\%$	FOR FURTHER PRODUCT OPTIONS PLEASE REFER TO THE OPTIONS PAGE.						

OPTIONS LIST for Behlke HTS switches with variable on-time

MBC	Mechanical Backward Compatibility to the previous switch models. All connectors, dimensions and attachment identical with the "historical" switch models such as HTS 81, 51, 31 ff.
HFB	High Frequency Burst: Improved burst capability of driver. Improved recovery time for shorter pulse spacing and connectors for external driver buffer capacitors, so far required.
HFS	High Frequency Switching: External supply of auxiliary driver voltage (50-350 VDC according to type). Necessary if the specified Max. Operating Frequency shall be exceeded. (2)
LP	Low Pass: Low pass filter at the control input. Propagation delay time will be increased by ~50 ns. Jitter + 500 ps. Improved EMC, better noise immunity and less critical wiring. (3)
UFTR	Ultra Fast Thermotriggger: Advanced temperature protection for the high-voltage switch. Switch shut down within 5 seconds if Pd(max) is exceeded by 300% @ $\Delta T=25K$ (50 to 75 °C)
UFTS	Ultra Fast Thermosensor: Temperature measurement directly on the power semiconductors by means of a special sensor with high electrical isolation and low thermal impedance.
TT-C	Customized Transition Time: Customized rise & fall times to meet individual design requirements. (2)
MIN-ON	Minimum On-Time: Individually increased Minimum On-Time to ensure a minimum on duration independtly of control signal. For safety relevant circuits.
MIN-OFF	Minimum Off-Time: Individually increased Minimum Off-Time to ensure a minimum off duration independtly of control signal. For safety relevant circuits.
ST	Stage Tapping: Connectors at the individual stages of stack in order to utilize single power semiconductors. To achieve fast rise times also at very low operating voltages (<0.01xVo).
LL	Low Leakage Current: Off-state current reduced to less than 10% of the specified value. Not available in connection with cooling fin options.
LN	Low Noise: Internal power driver modified for zero noise emission for a specific period of time. Relevant in conjunction with sensitive detector amplifiers (e.g. SEV/MCP) only. (2)
ISO-25	25 kV Isolation: Isolation Voltage increased to 25 kVDC. Housing dimensions may change for some models.
ISO-40	40 kV Isolation: Isolation Voltage increased to 40 kVDC. Housing dimensions may change for some models. Only in connection with option PT-HV.
ISO-80	80 kV Isolation: Isolation Voltage increased to 80 kVDC. Housing dimensions may change for some models. Only in connection with option PT-HV.
ISO-120	120 kV Isolation: Isolation Voltage increased to 120 kVDC. Housing dimensions may change for some models. Only in connection with option PT-HV.
I-PC	Integrated Part Components: Integration of small part components according to customers specifications (e.g. capacitors, snubbers, damping resistors, diodes, opto couplers). (2)
I-FWD	Integrated Free-Wheeling Diode: Built-in parallel diode with short recovery time. In connection with inductive load only.
I-FWDN	Integrated Free-Wheeling Diode Network: Built-in parallel diode plus serial blocking diode with short recovery time. In connection with inductive load only.
ITS	Integrated Thermo Sensor: Integrated temperature sensor for external temperature measurements according to customers specifications (NTC, KTY, PT-100 etc).
LS-C	Shielded Socket for Control Connection: Shielding for all inputs. Input impedance 100 Ohm. With 1m (3ft) linkage cable and 2nd socket. Improved noise immunity. (3)(4)
PT-C	Pigtails for Control Connection: Flexible leads (l=75 mm) with PCB connector (AMP-modu) instead of pins. Recommended for modules with options CF & GCF.
PT-HV	Pigtails for HV Connection: Flexible leads with cable lugs. For increased creepage. PT-HV is standard for all types with >25 kV switching voltage. Not for extremely fast circuits.
SEP-C	Separated Control Unit. Control unit with LED indicators in a separate housing (dimension 79 x 38 x 17 mm). Linkage cable (<1m) with plug. Control unit with soldering pins or pigtails.
PC	Pulser Configuration. Switch combined with custom specific part components. Integrated in a plastic flange housing with HV connectors according to the customers specifications. (2)
UL94	Flame Retardant Casting Resin: Casting resin according to UL-94-V0. Minimum order quantity required. (2)
TH	Tubular Housing: Tubular instead of rectangular housing. Adaption to specific ambient conditions or in case of difficult assembly situations. (2)
FC	Flat Case: Height of standard plastic housings reduced to 19 mm or less. Not in combination with cooling options CF, GCF and DLC.
ITC	Increased Thermal Conductivity: Special moulding process to increase the thermal conductivity of the module. Pd(max) will be increased by approx. 20-30%. (2)
CF	Non-Isolated Cooling Fins: Standard sizes in categories I to VII according to model. Nickel plated copper 0.5 mm, fin height 35 mm. For air and oil cooling.
CF-1	Non-Isolated Cooling Fins d=1mm: Nickel plated copper 1.0 mm instead of 0.5 mm. The Max. Power Dissipation will be increased by ~80 %. For air and oil cooling.
CF-X2	Non-Isolated Cooling Fins enlarged by x2: Fin area enlarged by factor 2. Not relevant in connection with liquid cooling.
CF-CS	Non-Isolated Cooling Fins with customized shape: Individual shape to meet specific OEM requirements. (2)
CF-LC	Non-isolated Cooling Fins optimized for liquid cooling: Double fins, nickel plated copper, 0.5 mm thickness, height 20 mm.
CF-GRA	Non-isolated Cooling Fins made of graphite. Very light weight compared to copper at similar heat transfer, but reduced heat capacity. 0.5 or 1 mm thickness, height 35 mm.
CF-CER	Isolated Cooling Fins made of ceramics. Heat transfer properties similar to alumina. Forced convection recommended, height 35 mm.
CCS	Ceramic Cooling Surface. Top side of switching module made of special ceramics. Heat transfer properties similar to alumina. 10 kVDC isolation. Forced convection recommended.
C-DR	Cooling for Driver: Extra cooling for the driver and control electronics. Recommended in combination with option HFS at higher switching frequencies. (2)
GCF	Grounded Cooling Flange: Nickel-plated copper flange for High Power applications. Max. isolation voltage 40kV. Increased coupling capacitance CC.
ILC	Indirect Liquid Cooling: Liquid cooling for all kind of conductive coolants incl. mains water. Internal heat exchanger made of ceramics. For medium power and medium frequencies.
DLC	Direct Liquid Cooling: Internal cooling channels around the power semiconductors. The most efficient cooling for high frequency applications. For non-conductive coolants only.
HI-REL	High Reliability / MIL Versions: Available on request. (2)

(1) New option code: Data sheets may differ from this coding system (especially older ones) and do not indicate all possible options as per above table. (2) Please consult factory for detailed information. (3) These options are recommended for industrial applications, difficult noise environments, prototype experiments with flying leads and for users without special EMC design experience. (4) This option is not available in connection with Sync. I/O for parallel connection.

Examples of standard options and modifications for switches with variable on-time:

[Note: Mechanical drawings for the options below are available on request.](#)

